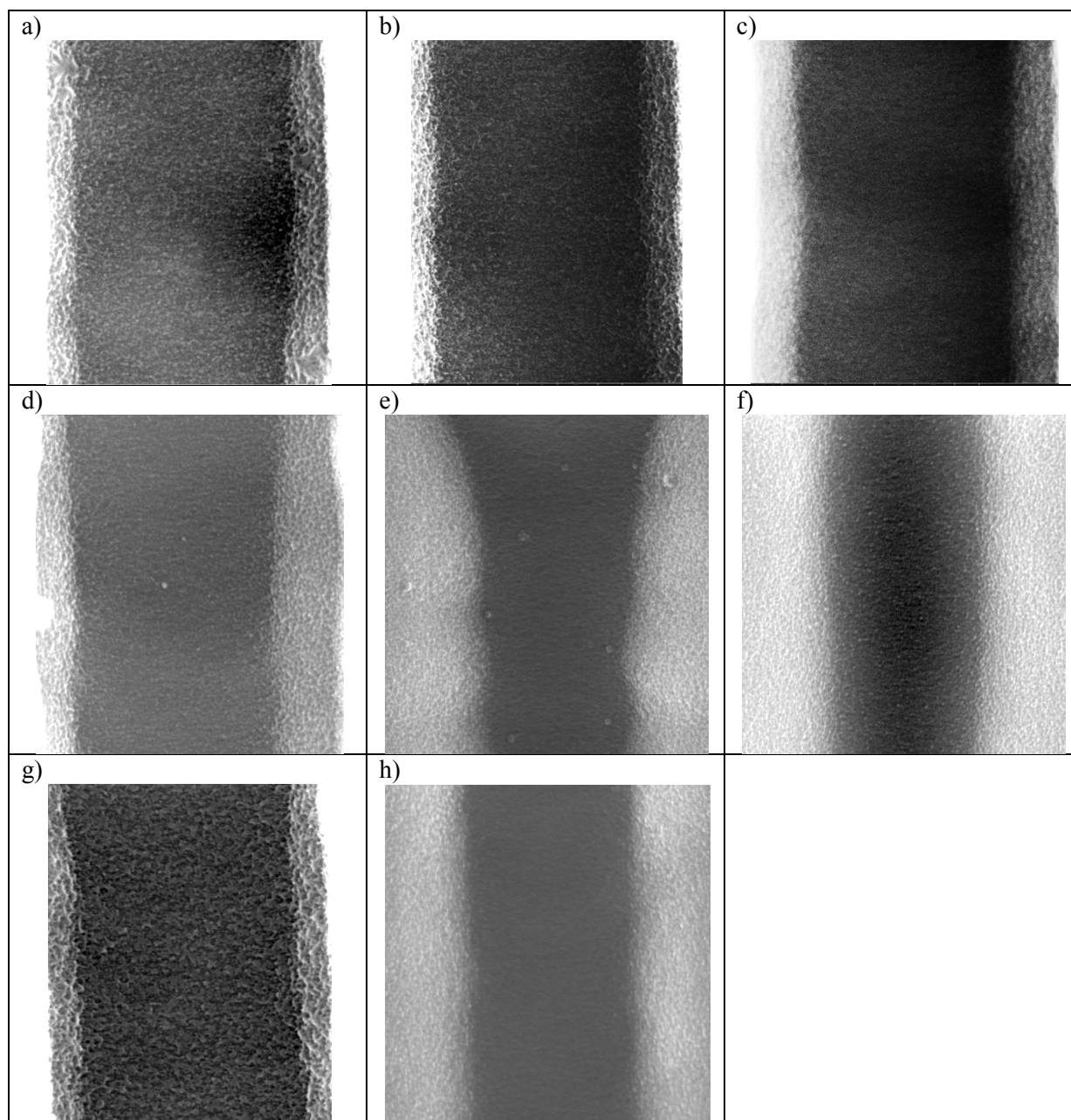


Pore size modulation in electrochemically etched macroporous p-type silicon monitored by FFT impedance spectroscopy and Raman scattering

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Supplementary information



S1. Examples of high magnification SEM images at wide sections of the pores of all the samples. a), b), c) prepared with 20 mA and 0, 1 and 2 g PEG respectively. d), e), f) prepared with 30 mA and 0, 1 and 2 g PEG respectively. g), e) prepared with 35 mA and 0, 1 and 2 g PEG respectively.